

# Theory and Practice of Solar Cells: A Cell to System Perspective

## Reliability of Solar Cells: Part I

M. A. Alam

alam@purdue.edu

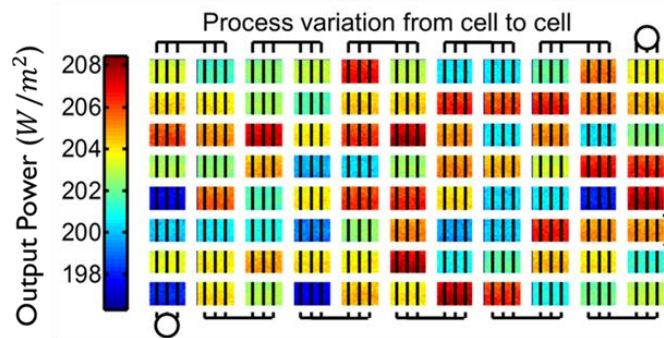
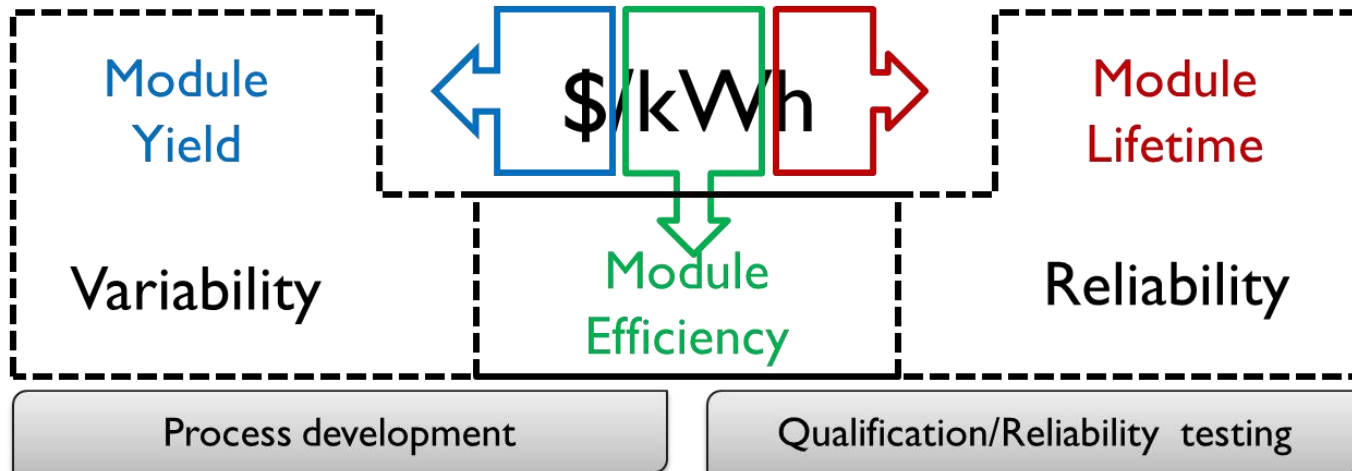
Electrical and Computer Engineering

Purdue University

West Lafayette, IN USA

# PV Reliability: A ROI Challenge

Competition with conventional energy sources



Alam, JPV, 2016



Osterwald, Sol. Mat. 2003

# Solar cell exposed to variety of weather conditions





# PV Field Failures Are Mounting

SECTIONS

HOME SEARCH

The New York Times

BUSINESS D

*Solar*

By TODD WOOD



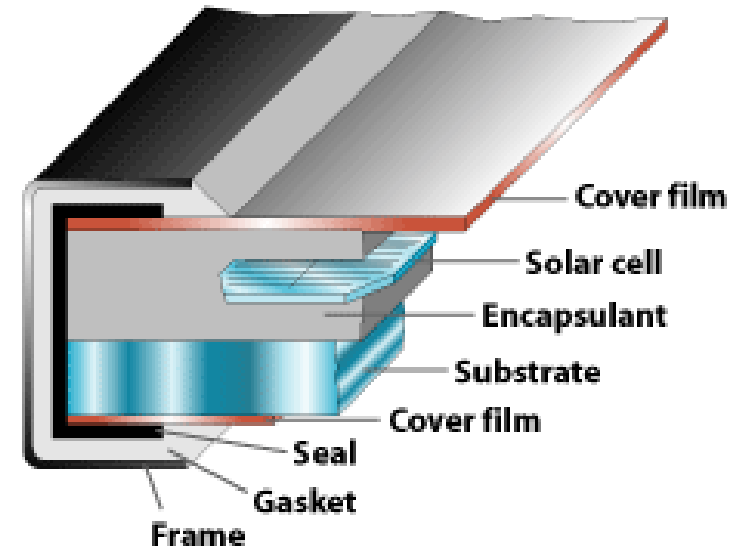
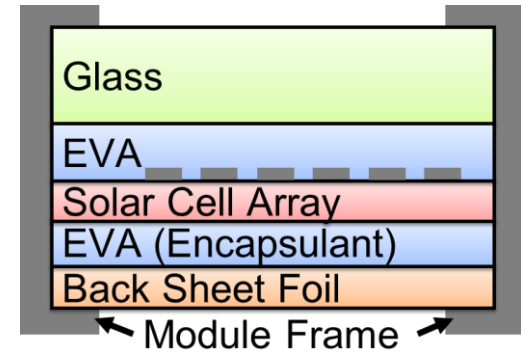
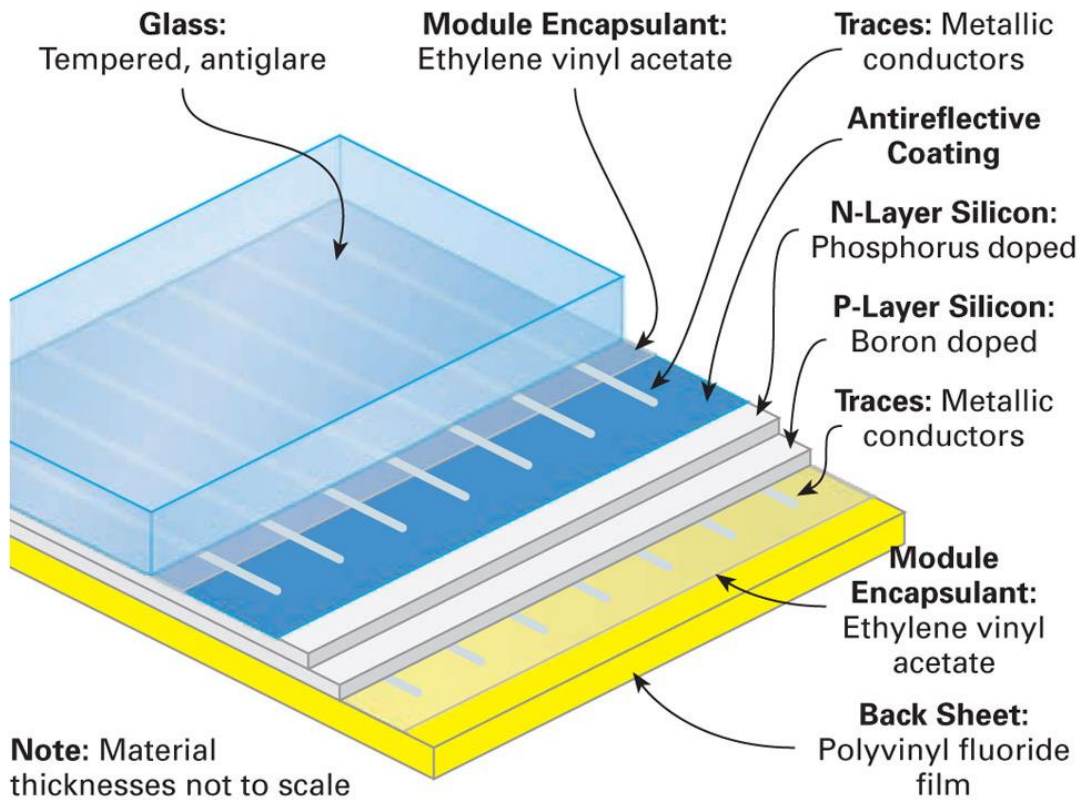
M. A. Alam, PV Lecture Notes

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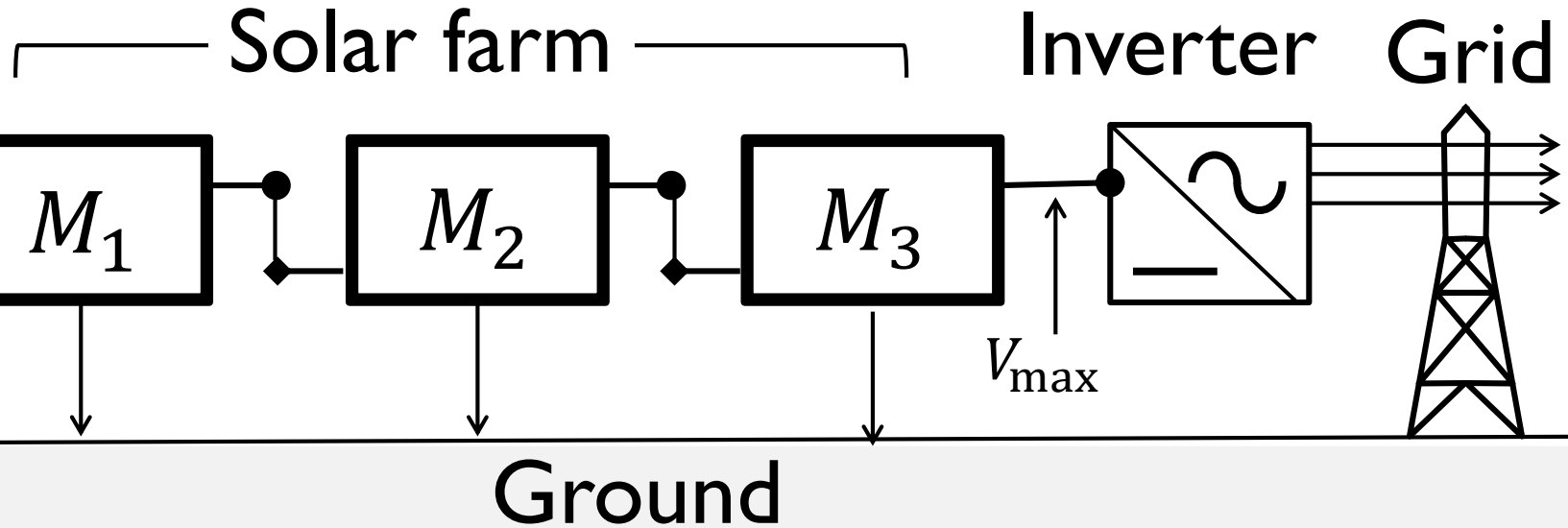
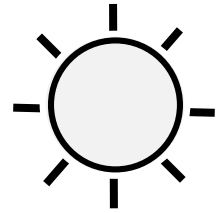
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# Fully assembled solar module



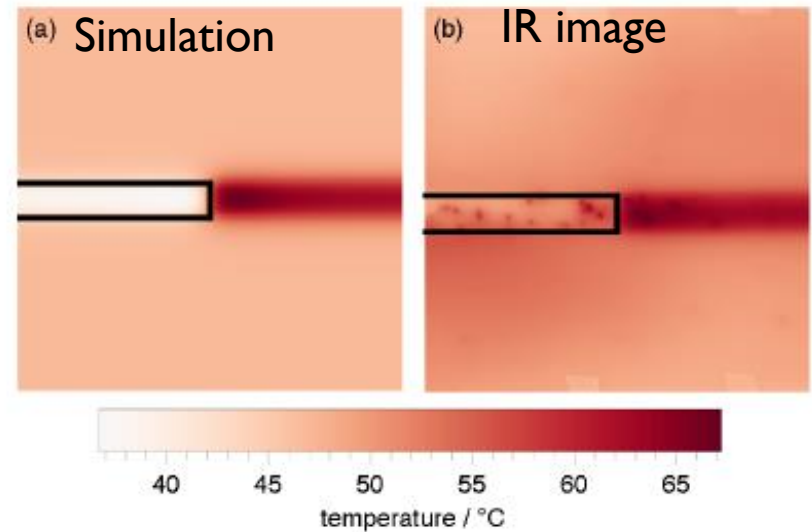
# Modules, inverter, and grid



# Outline

- 1) Background: Why does reliability matter
- 2) Three classes of reliability issues
  - Reversible (**Shadow**, Soiling)
  - Metastable (PID, LID)
  - Permanent (Yellowing, corrosion, cracking)
- 3) Forward and inverse reliability prediction
- 4) Conclusions

# A Shadow is Dangerous

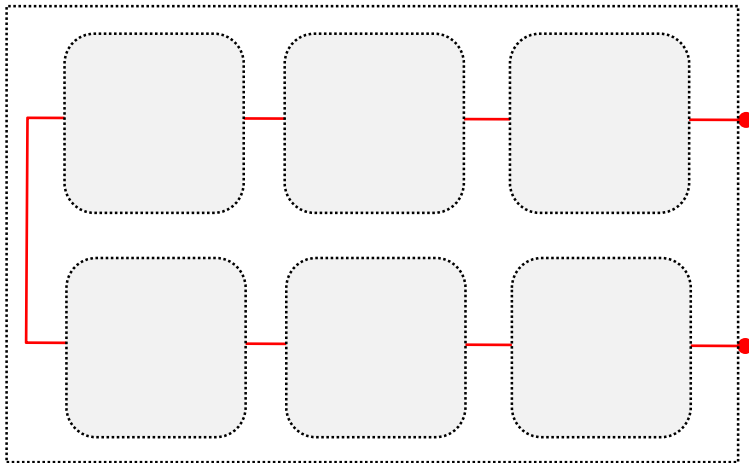


- simulation captures the temperature map of a shaded panel
- Pre-existing shunt causes local hot spots
- Self-heating due to shading leads to new shunt defects

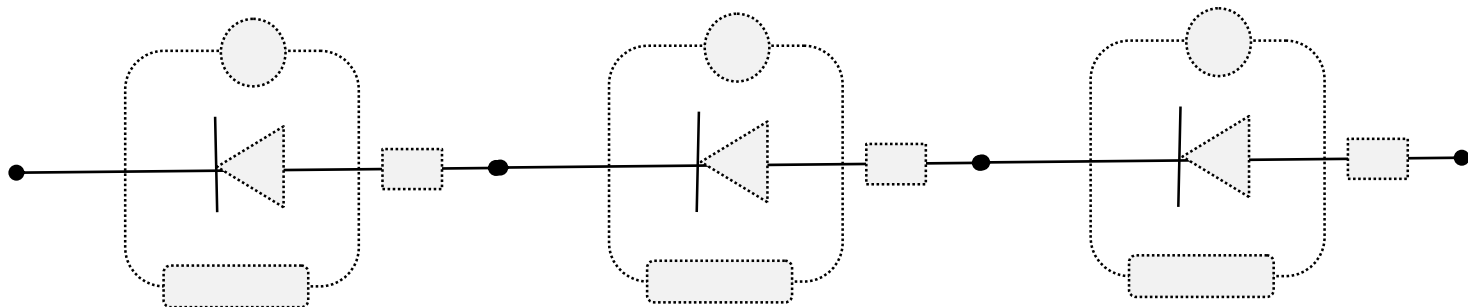
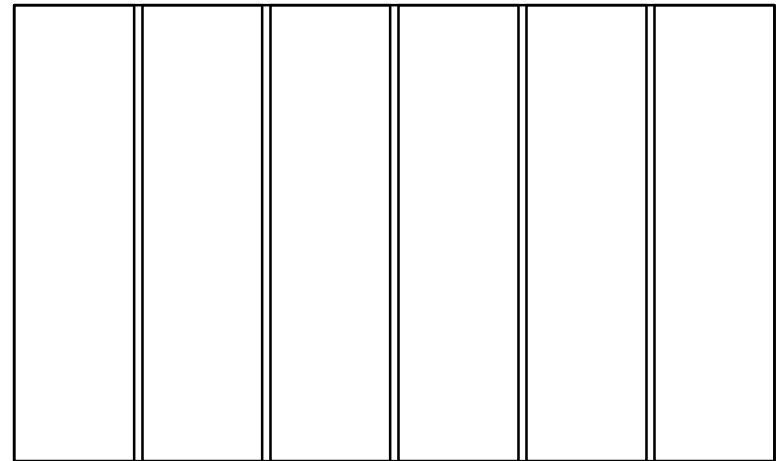


# Modules have cells connected in series

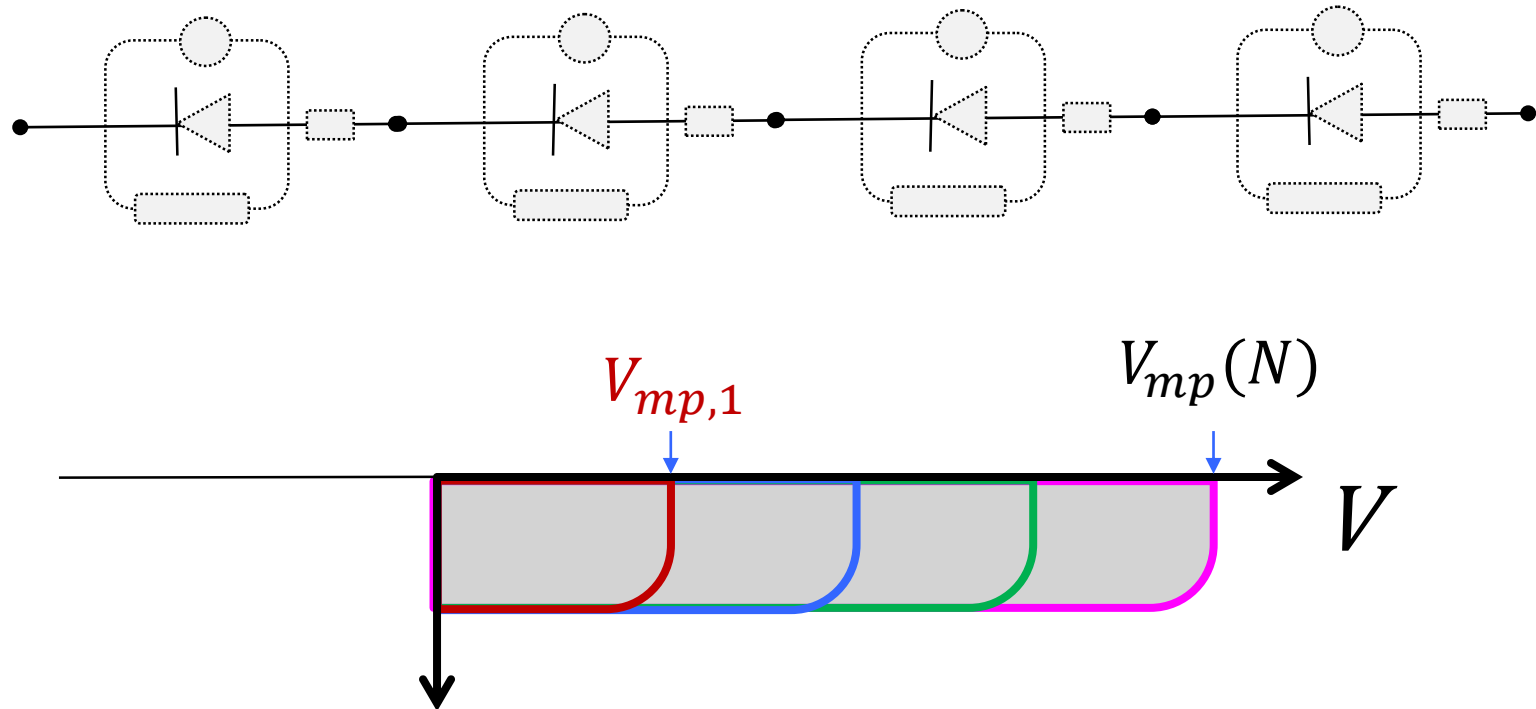
Si module



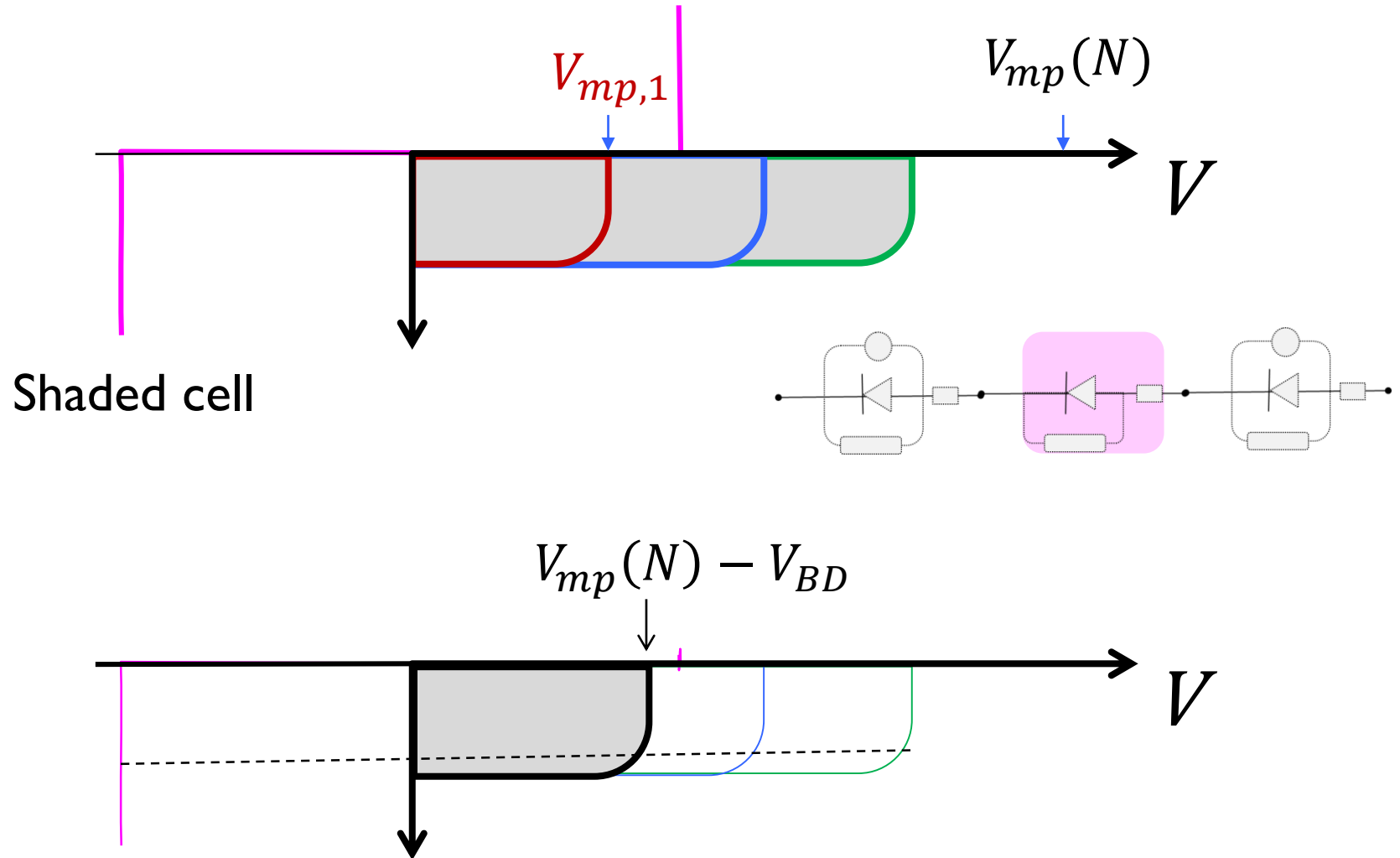
Thin-film module



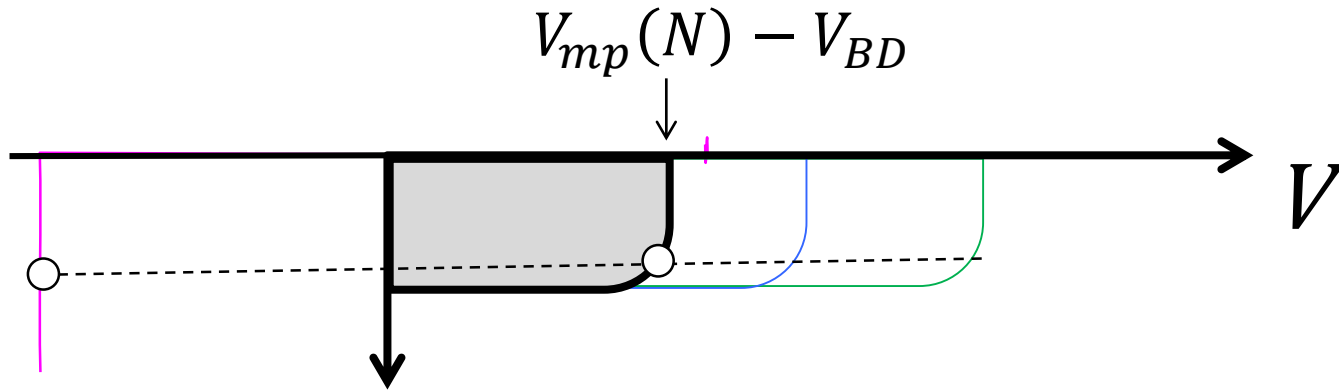
# I-V Characteristics of a module: Graphical representation



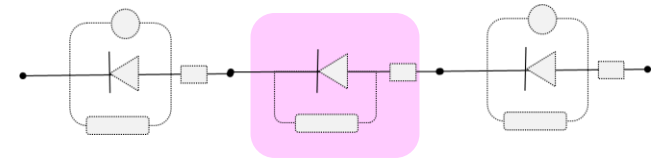
# One cell under full shadow



# Full shadow degradation



$$V_{op} = -V_{BR} + V_{mp}(N - 1)$$

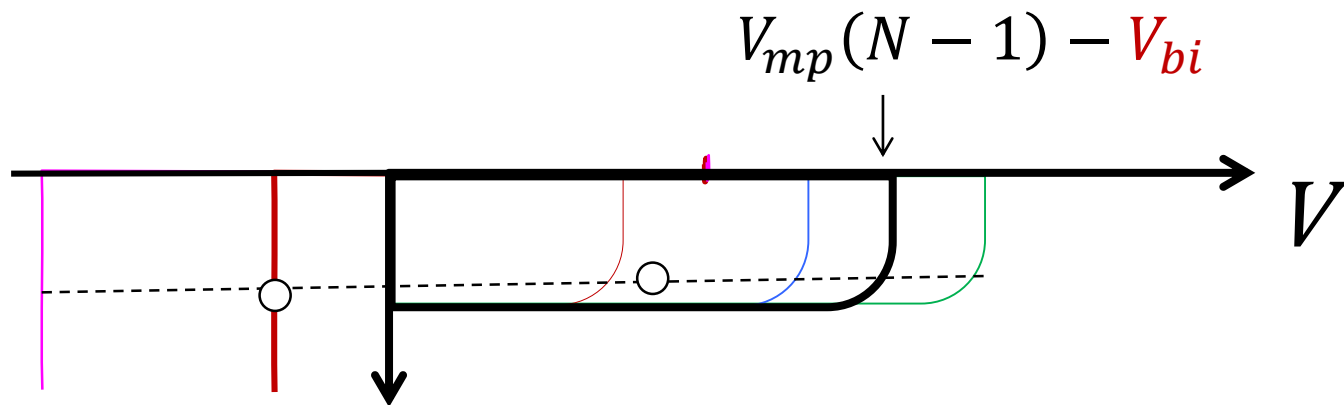
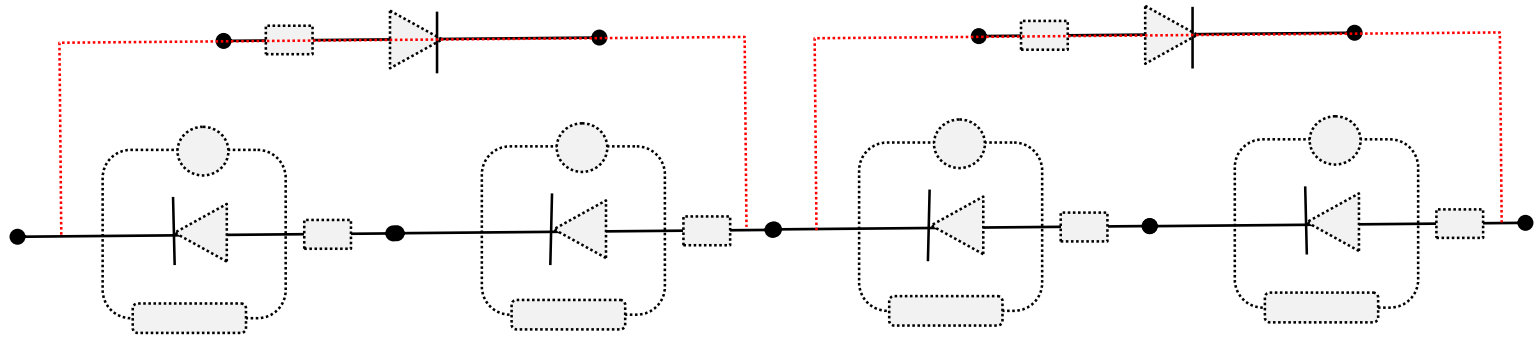


$$I = I_{ph}(N) - I_0(N - 1, R)(e^{\beta V} - 1)$$

$$P_{out} = V_{op} \times I_{ph} = I_{ph}(V_{mp}(N - 1) - V_{BR})$$



# Solution strategy: bypass-diode

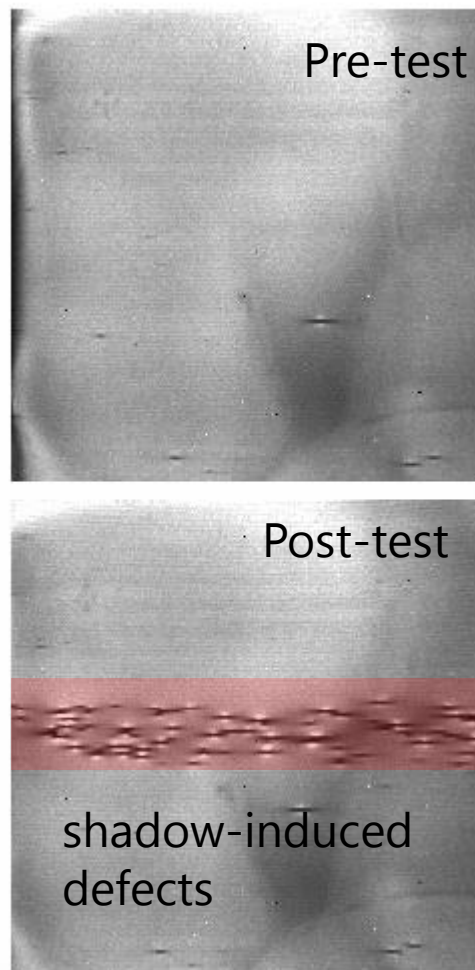
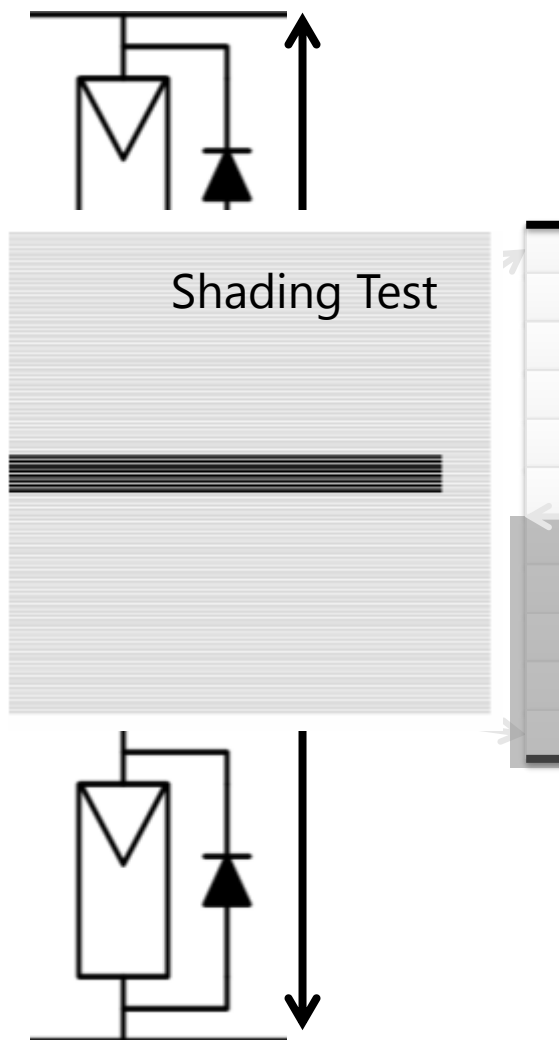


Little diode carrying a lot of current, may itself fail

$$P_{out} = V_{op} \times I_{ph} = I_{ph} (V_{mp}(N-1) - V_{bi})$$

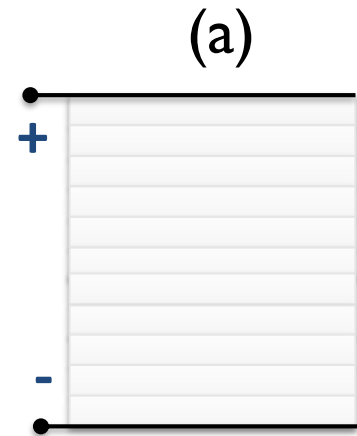
# Monolithic thin-film solar module

## Electroluminescence Images

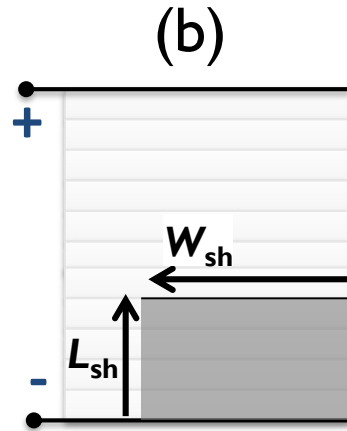


- Typical module architecture for thin film (**CIGS**, CdTe, etc.)
- Only **ONE** external bypass diode for one module (~100 cells)
- Bypass diodes can **NOT** prevent partial-shading induced gradation

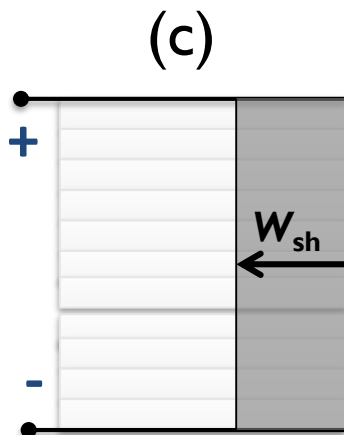
# Shapes and sizes of shadow



Fully illuminated

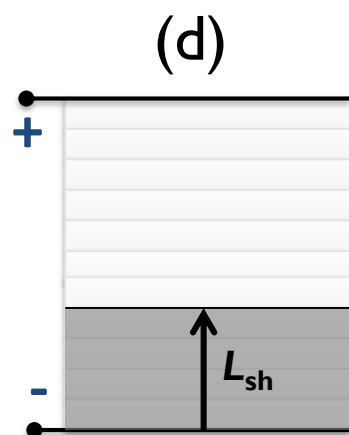


Partial Shadow



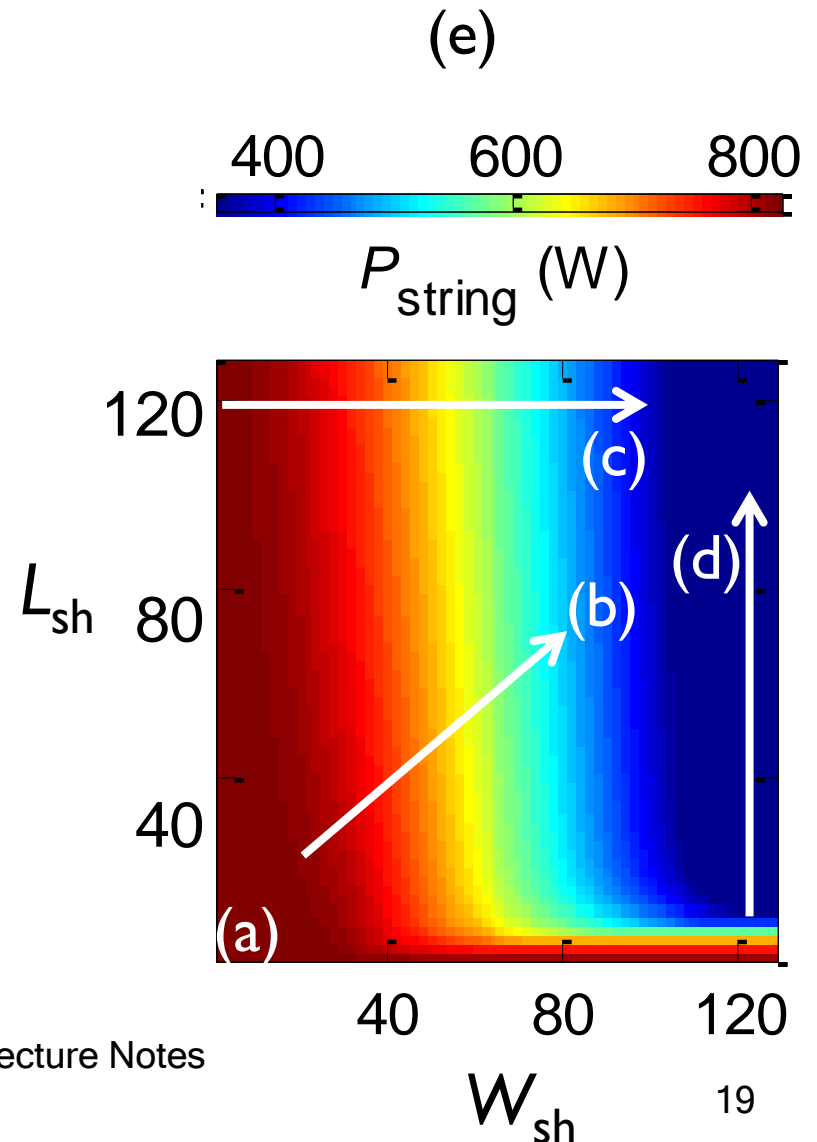
Full vertical

$$L_{sh} = L_{module}$$

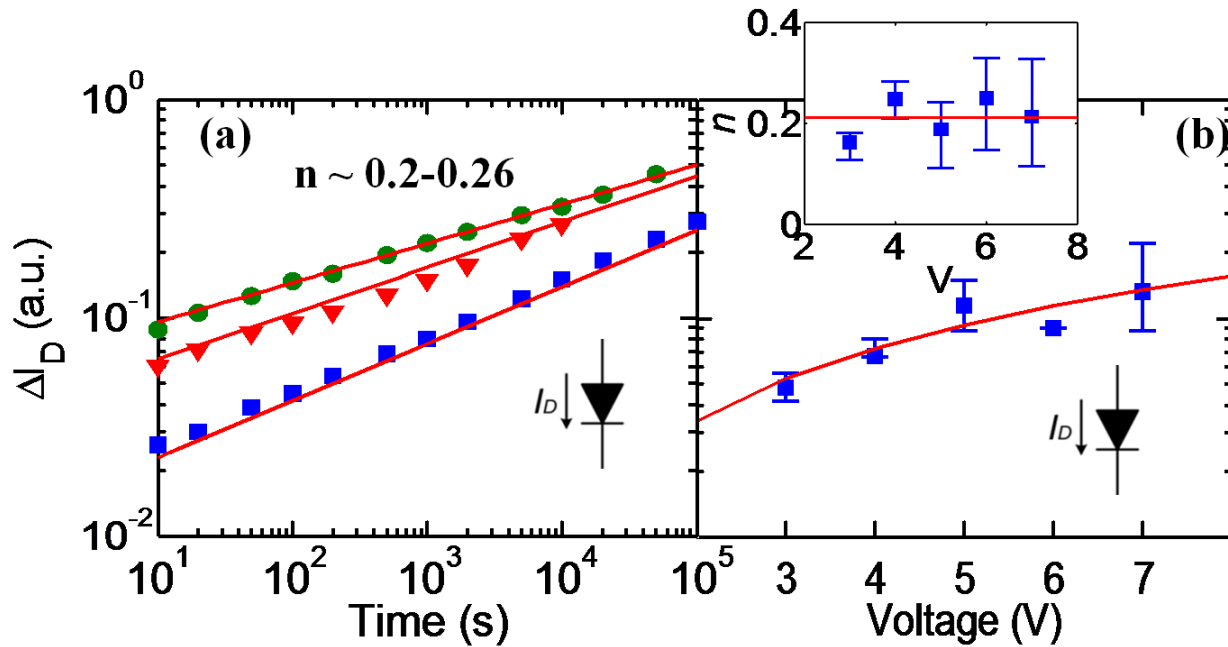
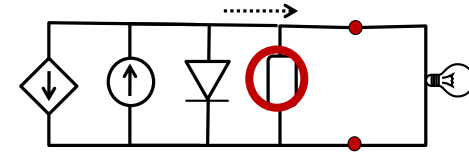


Full horizontal

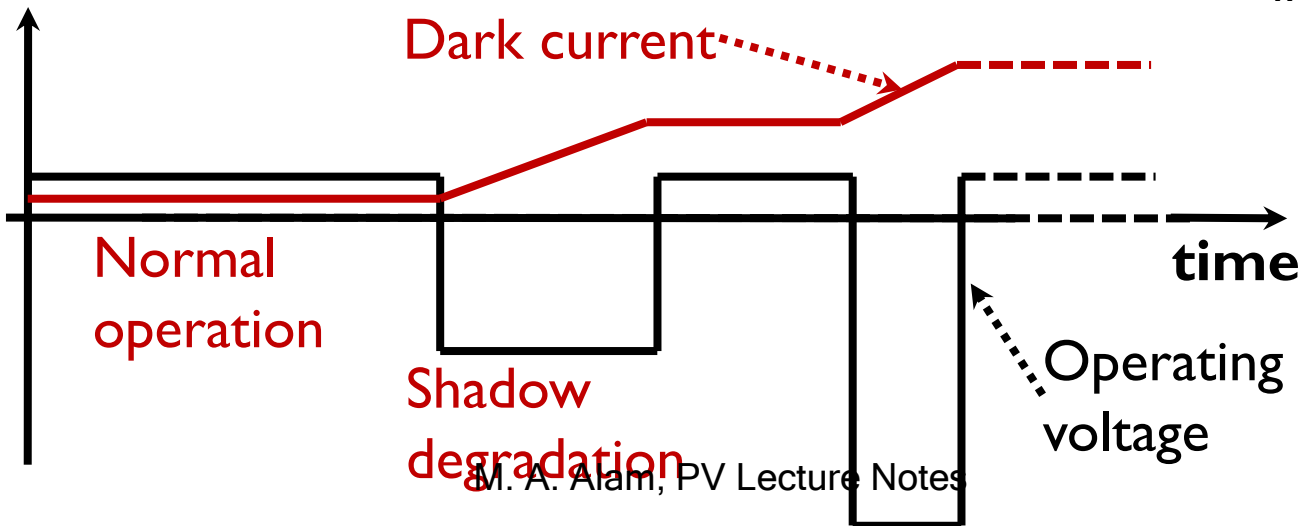
$$W_{sh} = W_{module}$$



# Shadow degradation

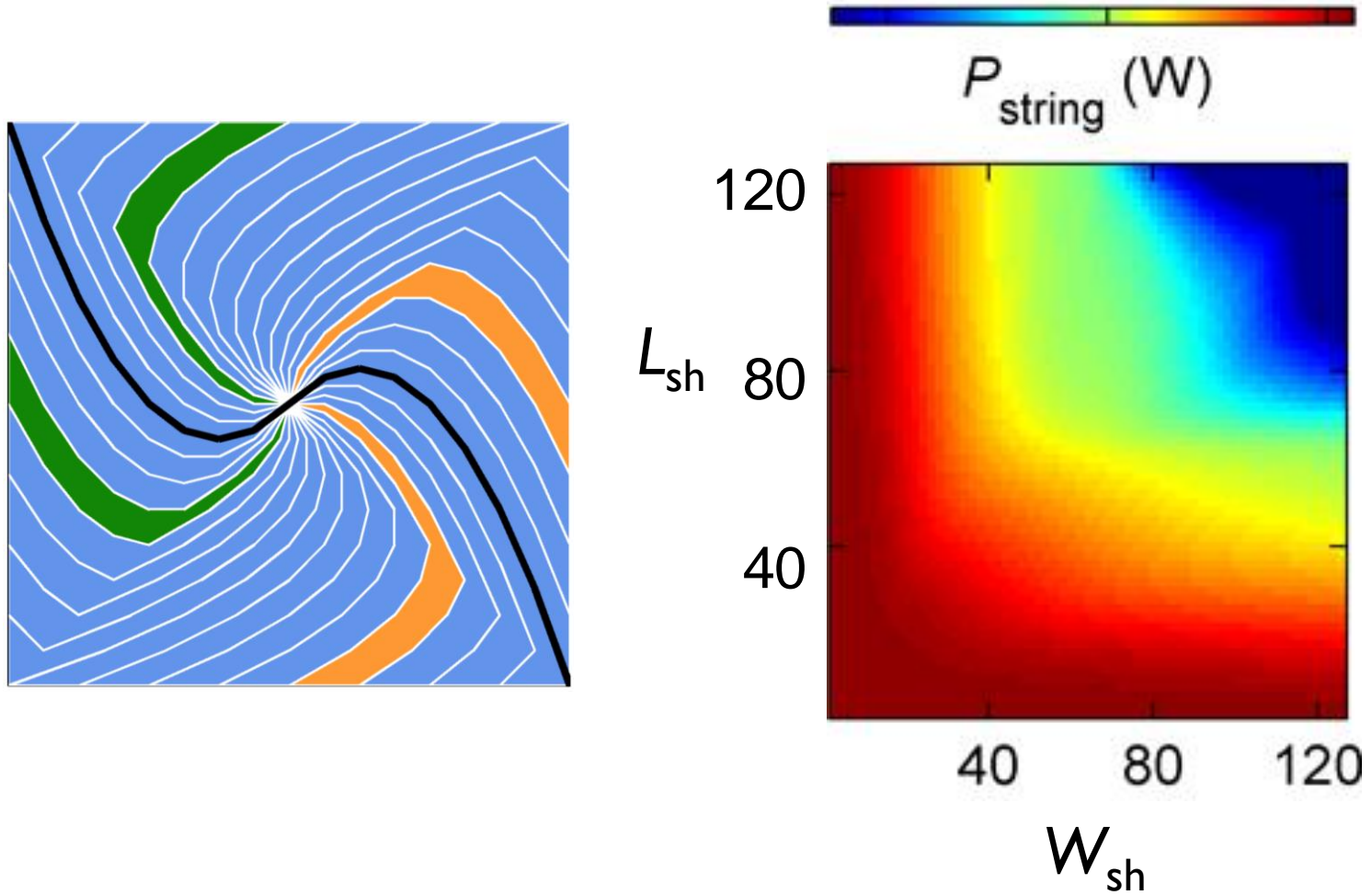


Dongaonkar et al.  
IRPS 2011





# Solution strategy: Geometry

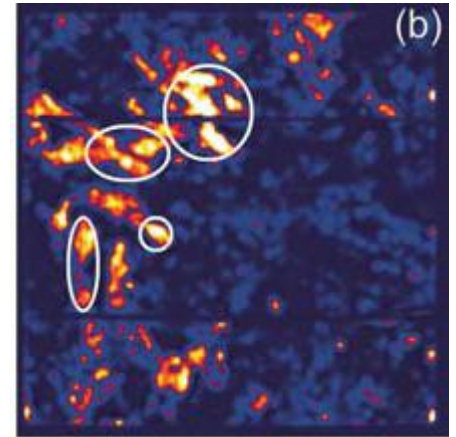


# Solution strategies

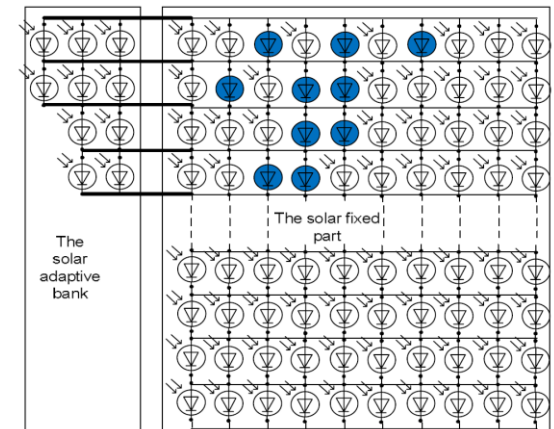
May lead to runaway process.

Solutions:

- *Device*: Characterized and qualified
- *Circuits*: Overvoltage Protection diode
- *Systems*: Redundant SRAM-like array



O. Breitenstein, *et al.*, *PSS*, 2009



D. Nguyen, *et al.*, *APEC*, 2008

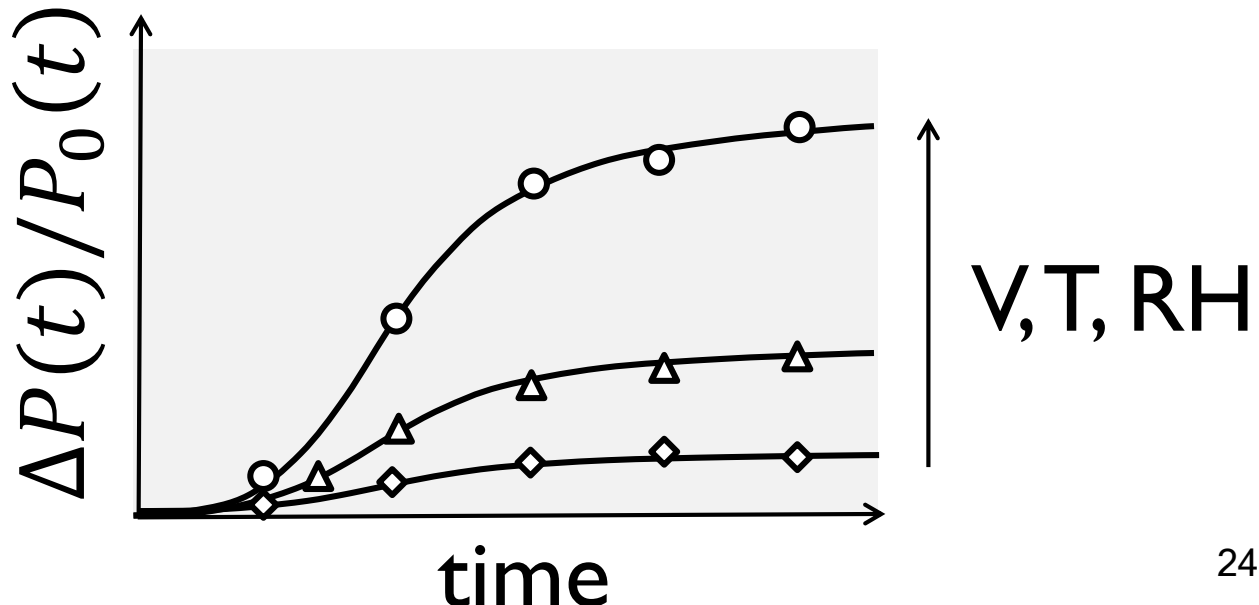
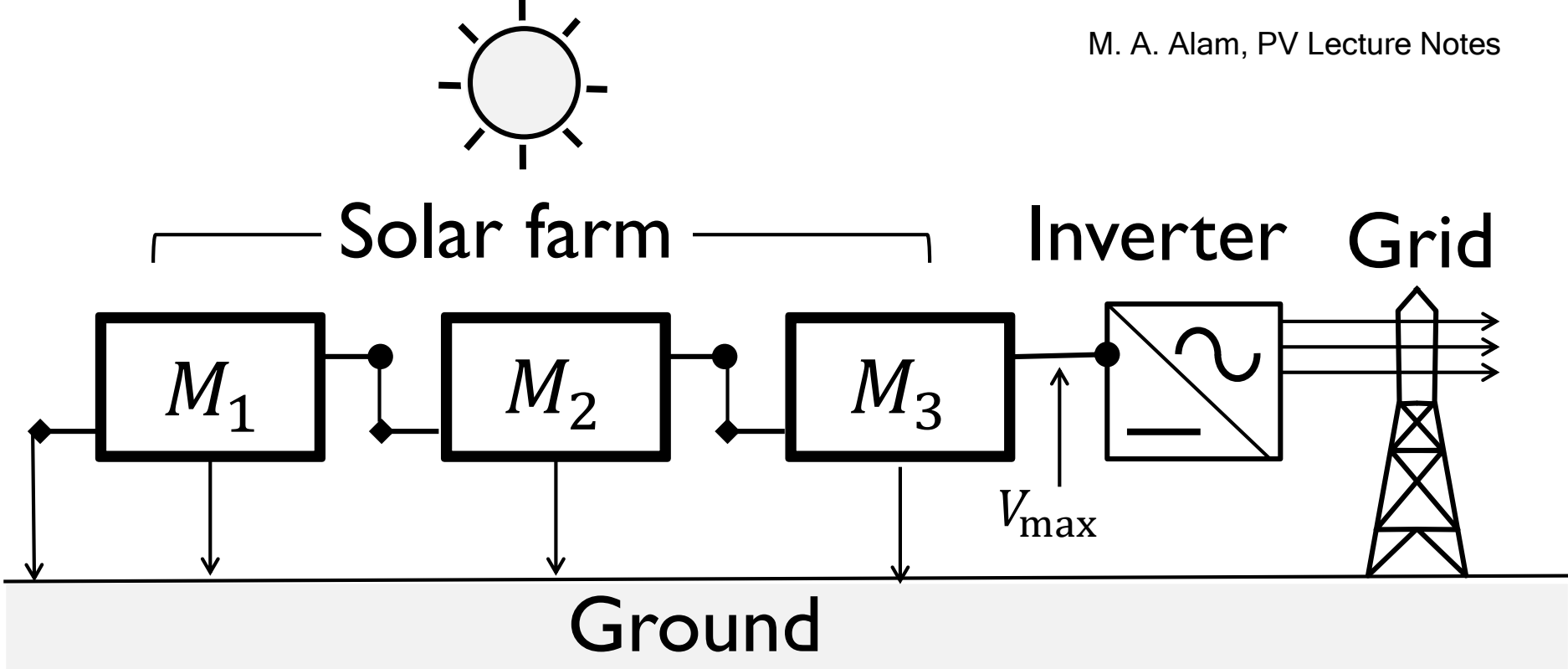
# Outline

1) Background: Why does reliability matter

2) Three classes of reliability issues

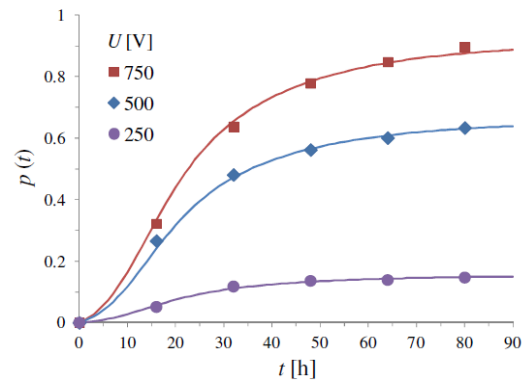
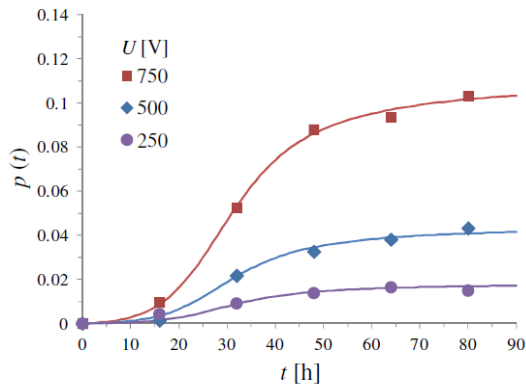
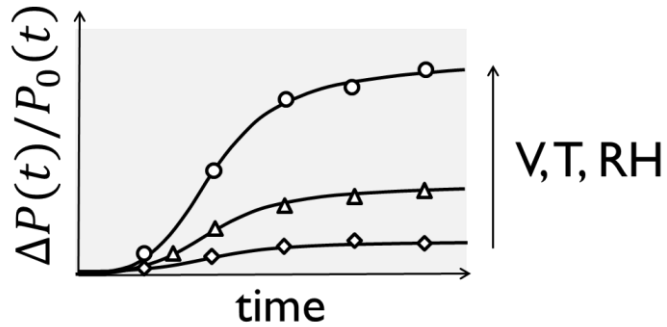
- Reversible (soiling, Shadow)
- Metastable (PID, LID)
- Permanent (Yellowing, corrosion, cracking)

4) Conclusions



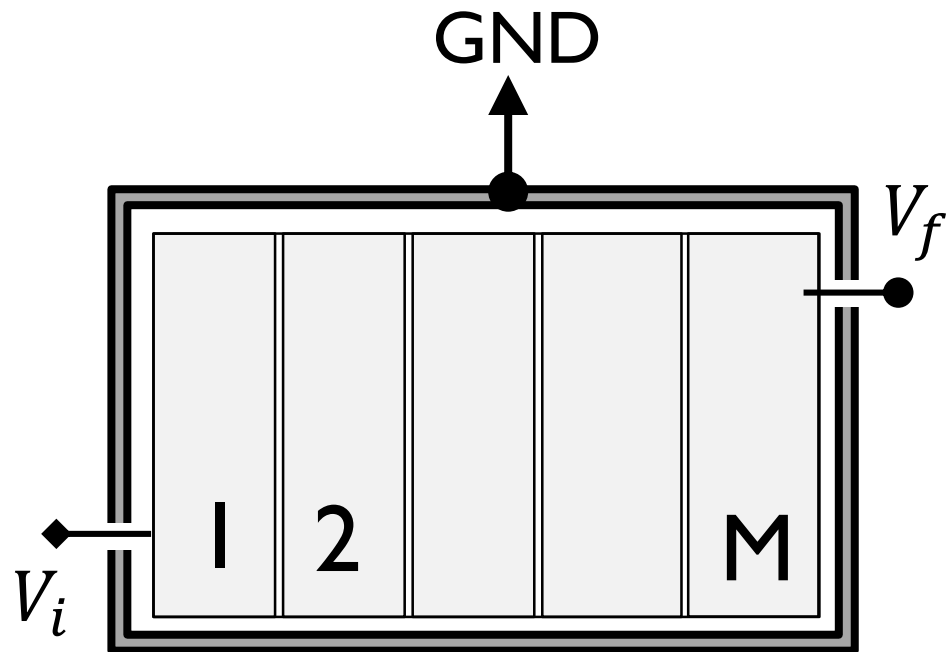
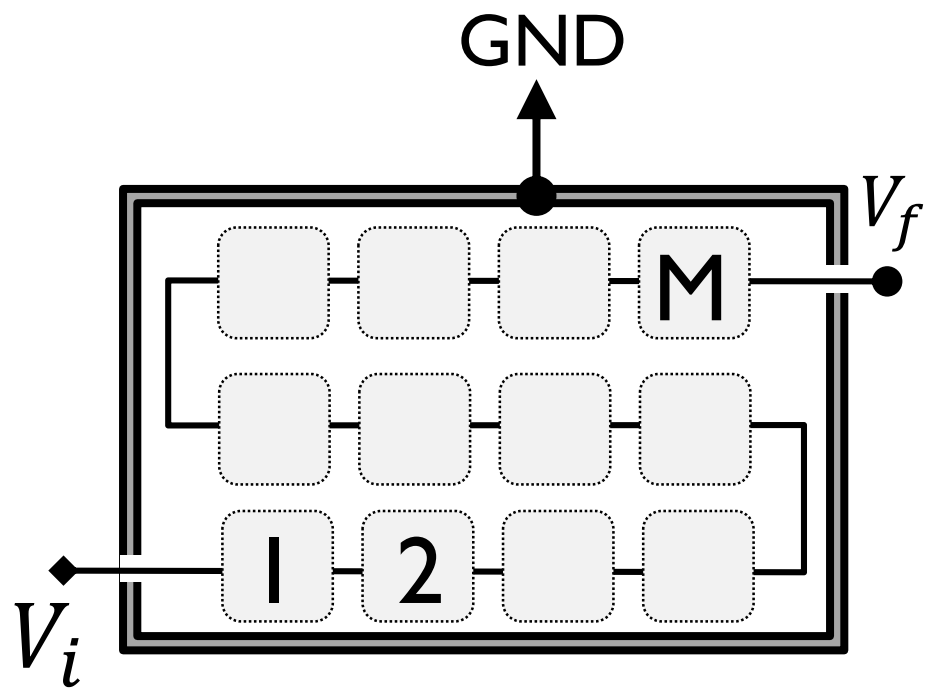


# PID Degradation

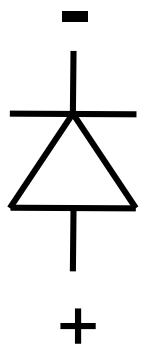


$$\frac{\Delta P}{\Delta P_{\infty}} = \frac{1}{1 + e^{-(t-t_H)R_D}}$$

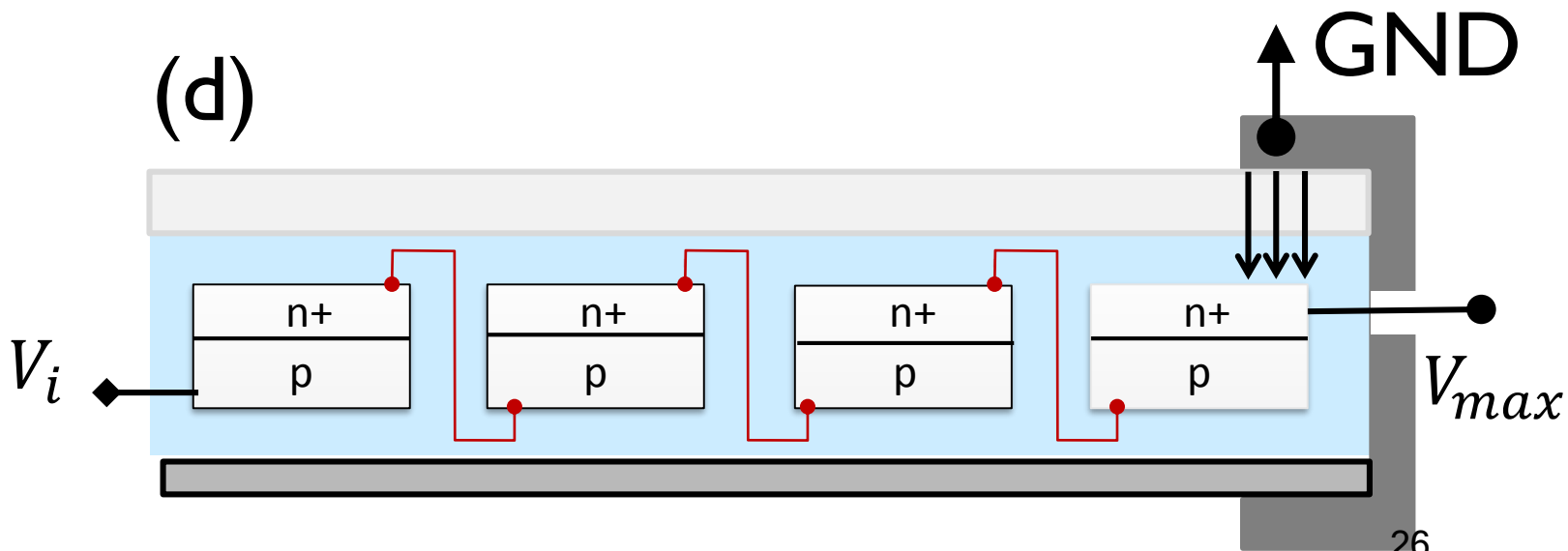
$$t_H = AV^n e^{-\frac{E_A}{k_B T}} [RH\%]^B$$



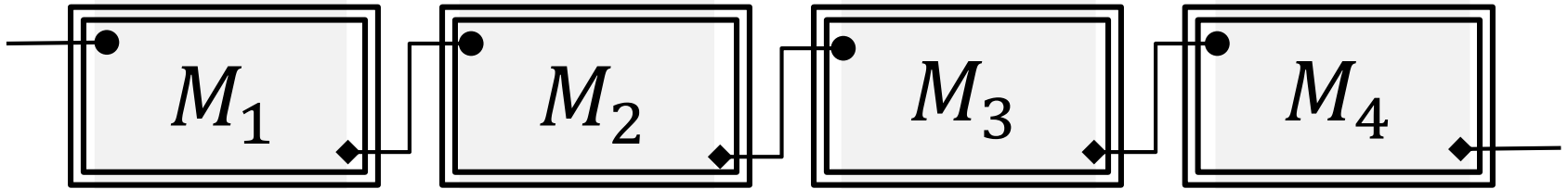
(c)



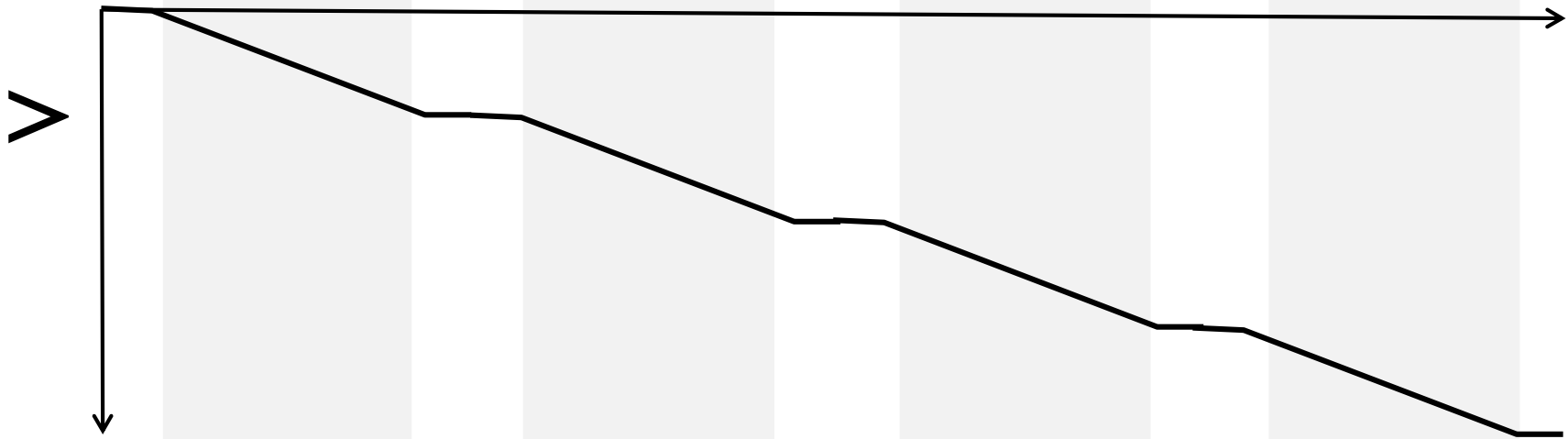
(d)



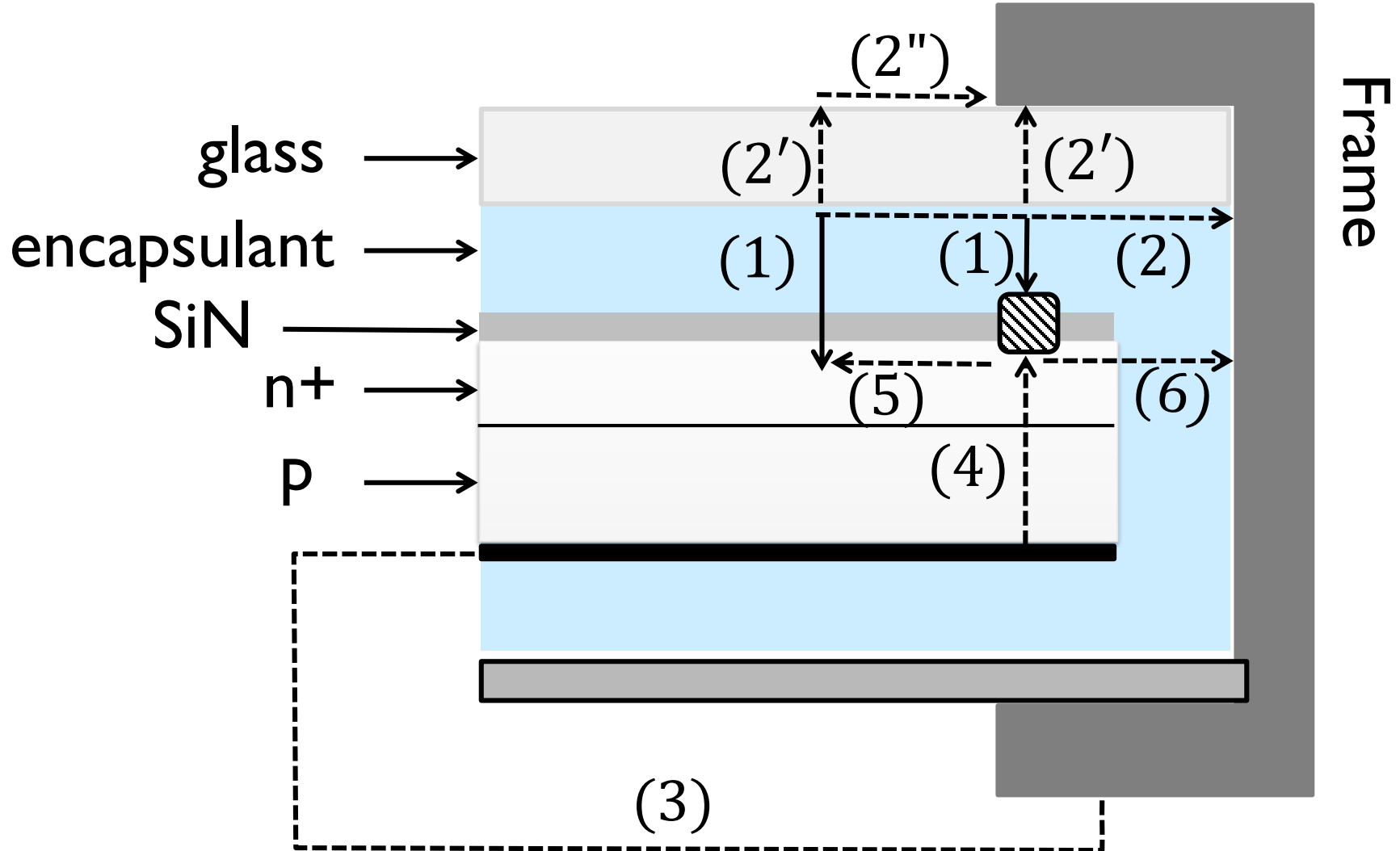
# Cascading voltage in a string



Module position

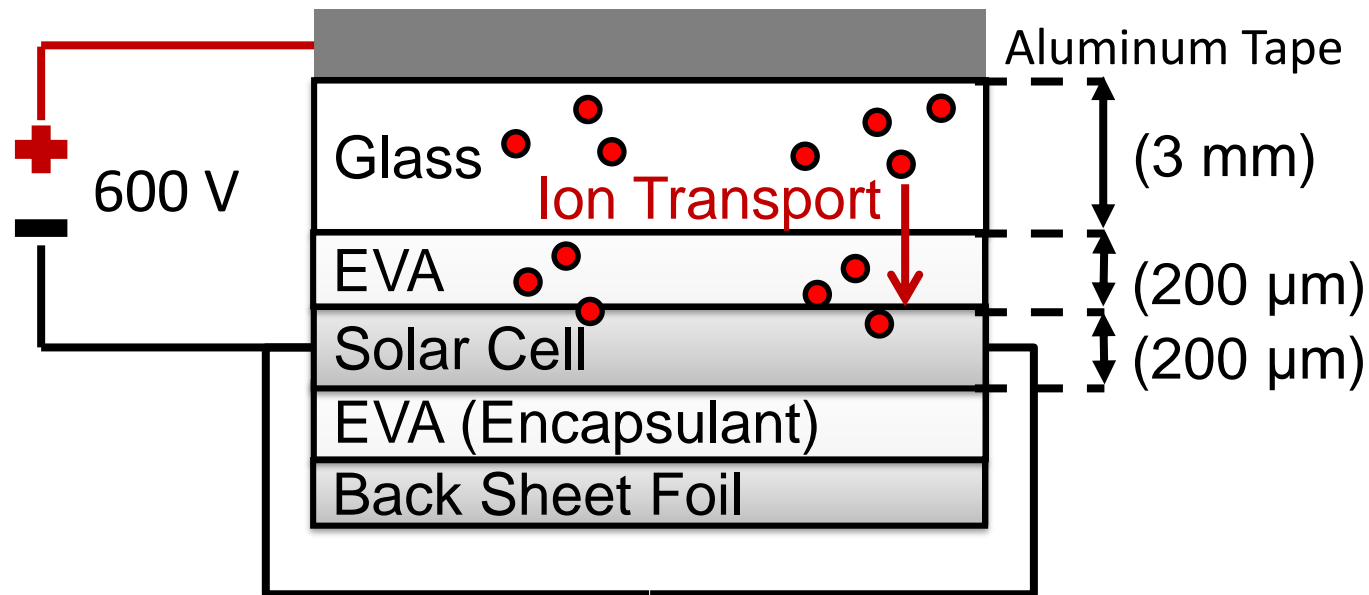


# Variety of PID leakage paths



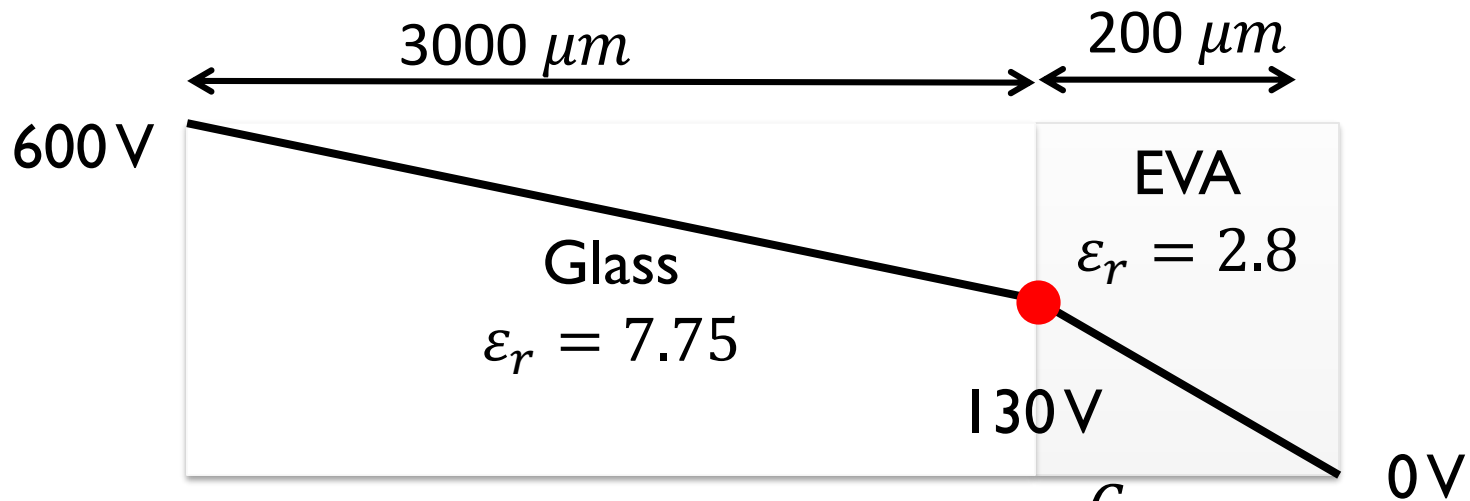
# A Model for PID Degradation

An aluminum tape covers the front surface



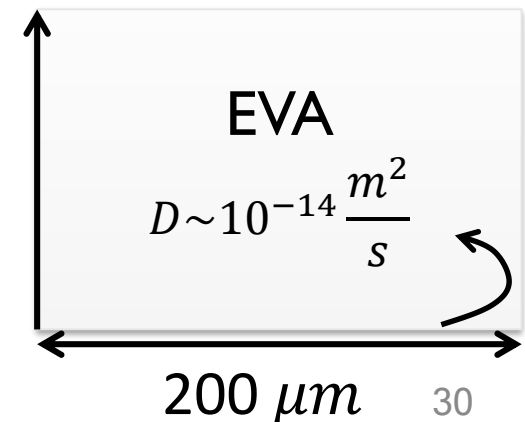
The tape makes the field inside the structure uniform and hence one dimensional transport simulation is done.

# Potential and Drift-Diffusion Geometry

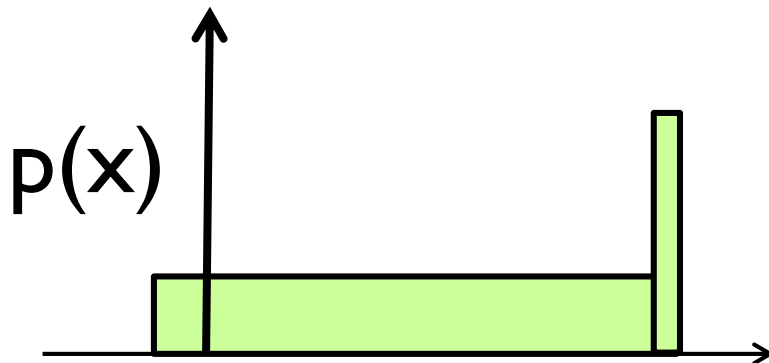
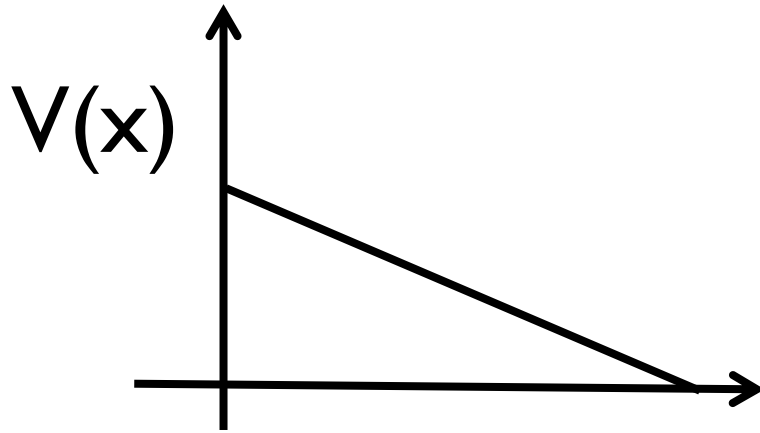


$$V_p = \frac{C_g}{C_p + C_g} V_{PID}$$

Transport Boundary Condition:  
 Left side: Constant  $10^{20} /\text{m}^3$   
 Right side: Reflective Boundary



# Linear Response: Low Na glass



$$Q_p (= qp_0 L_p)$$

$$J_{Na} = Q_p / t_p = qp_0 \mu_p V_p / L_p$$

$$\mu_p = \mu_0^* e^{-E_A / k_B T}$$

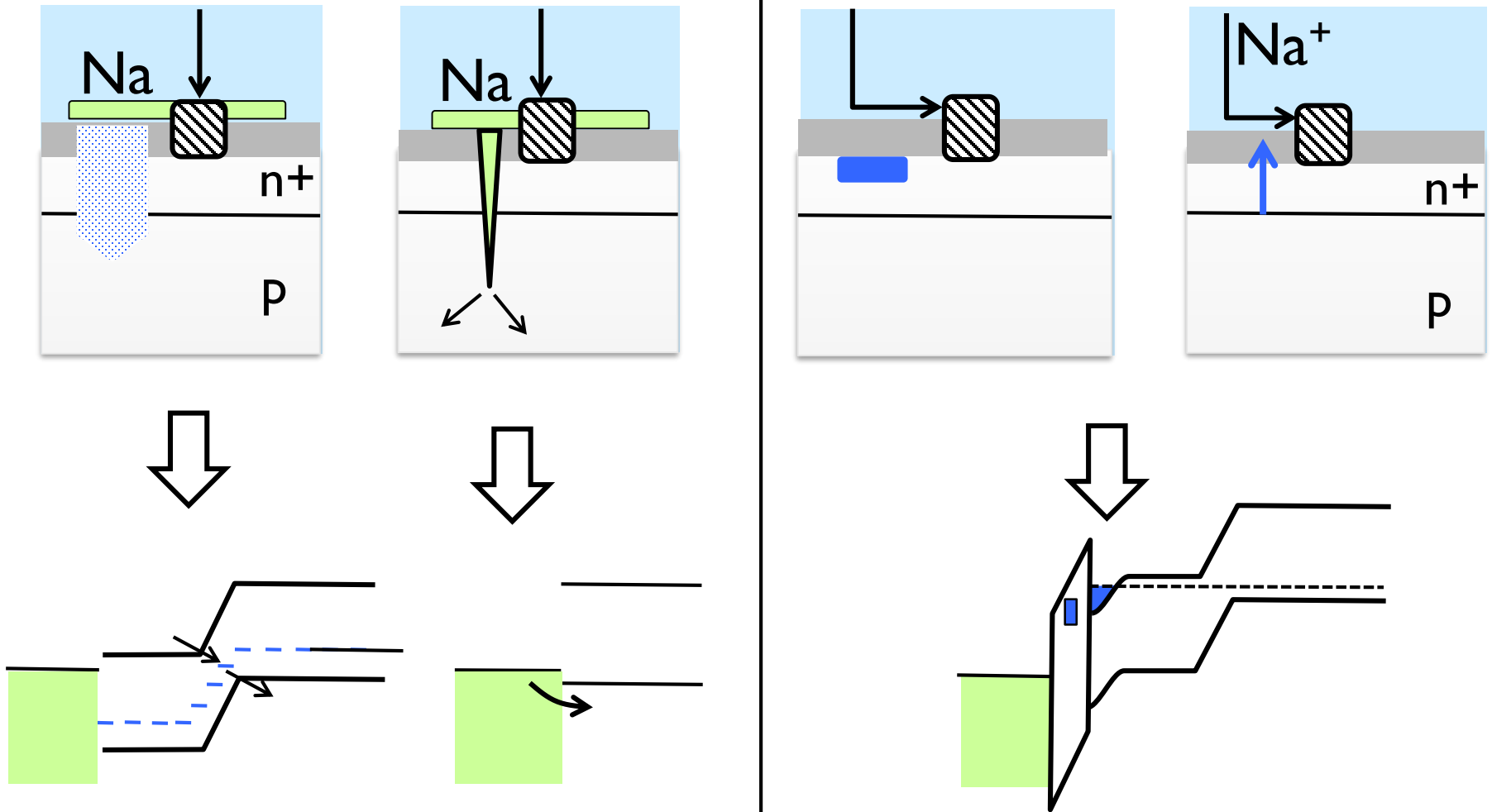
$$\mu_0^* = \mu_0 [RH\%]^B$$

$$R_D \propto J_{Na} = A e^{-E_A / k_B T} [RH\%]^B V_p$$

$$A \equiv qp_0 \mu_0 / L_p$$



# Types of PID degradation



# Conclusions

1. Solar cells must survive the weather outside for 25-40 years. Reliability is a key concern and a very important research topic.
2. The power loss may be reversible or irreversible. Many of the irreversible reliability issues arise from how the cells are series-connected to form a module and how modules are series-connected to form a string.
3. Shadow degradation and potential induced degradation are two very important reliability issues of a PV system. A set of solution methodologies have been developed to address these concerns.
4. We will discuss other reliability fundamental reliability issues, such as corrosion, and UV-degradation in the next lecture.

# Self-assessment Quiz

1. How does reliability affect the cost of electricity?
2. A partial shadow is more dangerous than a complete shadow. Explain.
3. Explain three different ways the effects of partial shadowing can be minimized.
4. Is partial shadow degradation reversible or irreversible?
5. Name the ion responsible for PID degradation.
6. Name two types of PID degradations discussed in this tutorial.
7. Explain why  $n^+-p$  vs.  $p^+-n$  have very different PID degradation. How does this polarity dependence implicate Na transport in creating PID?
8. Suggest two methods to suppress PID.